# CPI Electron Device Business - Microwave Power Module

The PTXM1000 microwave power module integrates a "super mini" traveling wave tube (TWT), linearizer, and an optimized high-density switch-mode power supply to create a single "drop-in" microwave amplifier block for any continuous wave (CW) application requiring the highest power and linear performance.

Integration of the TWT and its high-voltage power supply simplifies the system designer's task by eliminating TWT interconnects (and their associated safety and reliability hazards). Integration further reduces the overall system size, simplifying the installation process.

The MPM is factory adjusted to optimize TWT performance. No user adjustments are required, simplifying replacement and reducing replacement times in the field.

The MPM can be configured to incorporate a variety of TWT models, allowing the user to specify frequency and peak power parameters.

To learn more about CPI EDB's MPM capabilities, contact CPI EDB at ElectronDevices@cpi-edb.com or call +44 (0)20 8573 5555



The PTXM1000 microwave power module integrates a "super mini" travelling wave tube (TWT)

#### FEATURES:

- Frequency 13.75 14.5 GHz
- RF out power 110 W (+54.5 dBm)
- Duty cycle 100% (CW operation only)
- Single gain 53 dB Nom +/- 3 dB
- Weight 3.75 lbs max (1.7 kgs)

#### **BENEFITS**

- High power
- Compact & reliable
- Operation in the harshest military environments

#### APPLICATIONS:

- Radar
- Electronic Countermeasure (ECM) systems



RF	Cha	ıra	cto	rict	ics
	V				

Typical operating characteristics for the MPM incorporating a 13.75 to 14.5 GHz, 100 W TWT Note 1.

Frequency range  RF output power  (saturated)  Duty cycle  100% (CW operation only)  Small signal gain  Small signal gain stability  24 hours and over temperature range  Small signal gain variation  Frinput power  (for saturation)  Second harmonic at  saturation  Noise power density  (Beam On)  Maximum spurious PM  -40 dBc/Hz @ 10 Hz from carrier  -60 dBc/Hz @100 Hz from carrier  -80 dBc/Hz Max at 1 kHz from carrier
(saturated)  Duty cycle  100% (CW operation only)  Small signal gain  53 dB Nom +/- 3 dE  Small signal gain stability  24 hours and over temperature range  Small signal gain variation  -1.5 dB over  500 MHz bandwidth  RF input power  (for saturation)  Second harmonic at  saturation  Noise power density  -32 dBm/MHz max  (Beam On)  Maximum spurious PM  -60 dBc max  (Excluding +/-1MHz or  carrier frequency)  Single sideband CW equivalent phase noise  Power density  -40 dBc/Hz @ 10 Hz from carrier  -60 dBc/Hz @ 10 Hz from carrier
Duty cycle 100% (CW operation only)  Small signal gain 53 dB Nom +/- 3 dB  Small signal gain stability +/-2.0 dB max over  24 hours and over temperature range  Small signal gain variation +/-1.5 dB over  500 MHz bandwidth  RF input power 0 dBm typica  (for saturation)  Second harmonic at -15 dBc max with saturation matched load  Noise power density -32 dBm/MHz max  (Beam On)  Maximum spurious PM -60 dBc max  (Excluding +/-1MHz of carrier frequency)  Single sideband CW equivalent phase noise  Power density  -40 dBc/Hz @ 10 Hz from carrier  -60 dBc/Hz @100 Hz from carrier
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-90 dBc/Hz Max at 10 kHz from carrie
-100 dBc/Hz Max at >100 kHz from carrie
Noise figure 10 dB (typical

Output VSWR	2.0:1 max
3rd order 2 tone intermodu	ılation
-25 dBc max	a @ 2.5 dB back-off Note 2
AM/PM conversion	5 °/ dB typical

# **Prime Power Requirements**

Prime power

270 V DC per MIL-STD-704F (±10% normal operating range & abnormal voltage transient)

Power consumption

455 W @ 100 W RF

## **Connectors**

Primary power input	Nicomatic: 322YL015D51
connector	
Control and monitoring	ng Nicomatic:
connector D	221EP00D51-0003-3305+RF
RF input connector	SMA female
RF output connector	TNC female

# **Control and Monitoring**

Control inputs	HV on
	TWT beam on
Status outputs	Standby
	HV on
	Fault

### Notes:

1.5:1 max

- 1 Other characteristics are available to special order
- 2 Two equal tones spaced 10 MHz apart. MPM is fitted with a linearizer



Input VSWR

# Fault protection Extensive internal BIT incorporated to monitor most TWT parameters. MPM shuts down under fault conditions. TWT operating parameters can be monitored externally to aid fault location. An overtemperature trip is incorporated. Over temperature Fault outputs

radic outputs	
	summary fault
TWT monitor outputs	Cathode voltage
	Beam current
	Helix current
Heater warm-up	90 seconds from
	power on
Automatic restart	Auto-reset after fault is
	included (3 restarts) typical

Mechanical	
Mechanical outlin	ne
	190 x 120 x 30 mm excluding
	fixings and connectors
Weight	3.75 lbs (1.7 kg) max
Orientation	Any
Finish	Nickel plated
Markings/Labels	Type number
	Model number
	Serial number
	Connector ident
	Hazard warning
Cooling (	Conduction via baseplate, +85 °C

maximum temperature

# **Options (available on request)**

Alternative prime power 28 V, 115 VAC 3-phase (plug-in or stand-alone converters) Block up converter (BUC) RF output assemblies

Ambient temperatur	e -50 °C to + 85 °C
(operating)	
Ambient temperatur	e -55°C to + 100 °C
(non-operating)	
Baseplate temperatu	re 85 °C maximum
(MPM)	(operating)
Altitude (operating)	0 - 70,000 ft
- Vibration	MIL-STD-810G 514.6
(operational)	category 13
	MIL-STD-810G 514.6
(storage and transit)	category 8 & 6
Shock	MIL-STD-810G 516.6
	procedure functional shock
Acceleration	MIL-STD-810G table 513.6-II
	(Aircraft operational)
	MIL-STD-810G table 513.6-I
	(Aircraft structural)

Humidity (operation & storage) MIL-STD-810G part one C-I, constant high humidity (B1) EMC performance

MIL-STD-461E – requires external EMC filter



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For more detailed information, please refer to the corresponding technical description if one has been published, or contact CPITMD Technologies. Specifications may change without notice as a result of additional data or product refinement. Please contact CPI TMD Technologies before using this information for system design.